

David Na	Emitting Color	Material	Lens Type	Iv (IF = 20mA)		Viewing Angle
Part No.				MIN (mcd)	TYP (mcd)	<b>2</b> θ 1/2
	Super brightness green	AlGainP	Water Clear	30	70	120°

APPROVE:	CHECKED:	DRAWN:	DATA NO:	SCALE:
T .	~.			15:1
Lin	Simon	$oxedsymbol{ extit{C}ui}$	P-M-ES-AT006-HL	DATE:
				2002/7/8







Absolute maximum ratings		QG	Green	Unit	
$(TA=25^{\circ}C)$		(AlC	aInP)		
Reverse voltage	Vr			5	V
Forward current	IF		3	0	mA
Forward current(Peak)	I FP		10	)()	mA
1/10 Duty Cycle,0.1ms Pulse Width	<i>D</i>				
Power dissipation	Pd		5	0	mW
LED LAMPS:					
Operating temperature	Top		<b>-</b> 40~	+85	$\begin{array}{c c} & C \\ C \end{array}$
Storage temperature	$T_{ST}$		-40~	+85	°C
LED DISPLAYS:					
Operating temperature	ΤA		-40~	+85	°C
Storage temperature	$T_{\rm STG}$		-40~		°C

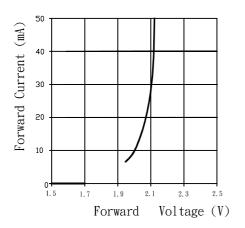
Operating characteristics (TA=25°C)		QG Green (AlGaInP)	Unit
Forward voltage(typ.) IF =20mA	VF	2.2	V
Forward voltage(max.) IF =20mA	VF	2.6	V
Reverse current(max.) V <sub>R</sub> =5V	IR	10	uA
Wavelength at dominant emission(typ.)  IF =20mA	λD	575	nm
Wavelength at peak emission(typ.)  IF =20mA	λР	574	nm
Spectral line half-width IF =20mA	$\Delta$ $\lambda$	25	nm
Capacitance VF =0V ,f =1MHz	С	20	pF

APPROVE:	CHECKED:	DRAWN:	DATA NO:	SCALE:
Lin	Simon	Izmei	P-O-AB-00011-03	DATE: 2003/05/09

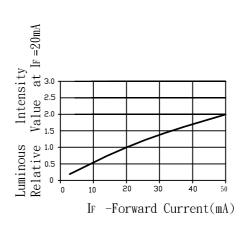




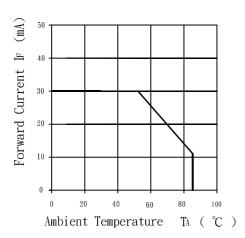




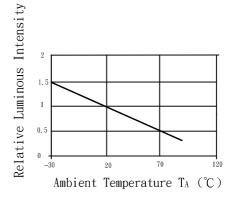
Forward Current Vs. Forward Voltage



Luminous Intensity Vs. Forward Current



Forward Current Derating Curve



Luminous Intensity Vs. Ambient Temperature

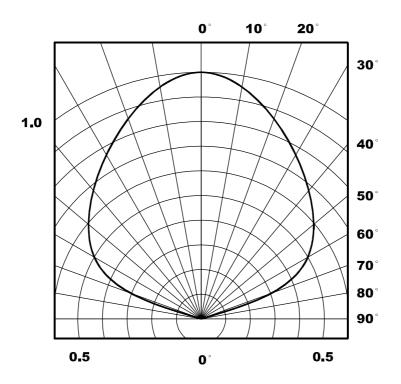
APPROVE:	CHECKED:	DRAWN:	DATA NO:	SCALE:
Lin	Simon	Izmei	P-0-AC-00008-02	DATE: 2002/08/20







**120**°



View Angle 2  $\theta$  1/2=120 $^{\circ}$ 

APPROVE:	CHECKED:	DRAWN:	DATA NO:	SCALE:
Lin	Simon	Izmei	P-O-AF-00012-02	DATE: 2002/03/19

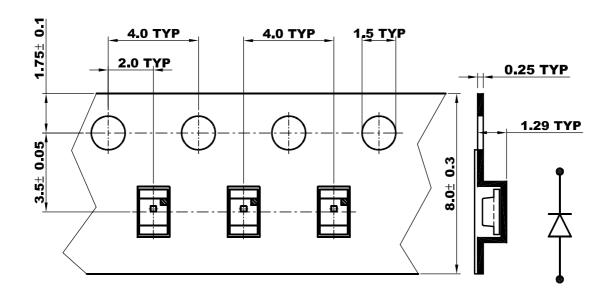




UNIT:MM

TOLERANCE:± 0.25

TYPE PACKAGE:2000 OR 1000PCS/REEL REEL"T":14mmTYP



APPROVE:	CHECKED:	DRAWN:	DATA NO:	SCALE:
Lin	Simon	Grmei	P-M-AD-00006-04	6:1 DATE:
		<i>ð</i>		2002/09/30

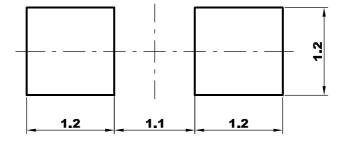




UNIT:MM

The following soldering patterns are recommended for reflow-soldering:

For reflow soldering



APPROVE: CHECKED: DRAWN: DATA NO: SCALE: 20:1

Lin Simon Cui P-M-AE-00004-02 DATE: 2003/02/10

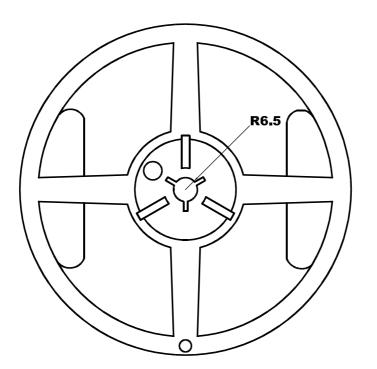


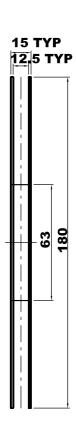


#### **REEL SPECIFICATIONS**

UNIT:MM

TOLERANCE:± 0.25





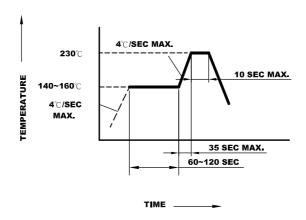
APPROVE:	CHECKED:	DRAWN:	DATA NO:	SCALE:
				1:2
Lin	Simon	Szmei	P-O-BA-00002-01	DATE:
				09/24/2001





# **SOLDERING**

# SMT REFLOW SOLDERING INSTRUCTIONS



	SOLDERING INSRTUCTIONS						
	DIP AND WAVE SOLDERING			IRON SOLDERING(WITH 1.5mm IRON TIP)		nm IRON TIP)	
TYPES	TEMPERATURE OF THE SOLDERING BATH	MAXIMUM SOLDERING TIME	DISTANCE FROM SOLDER JOINT TO CASE	TEMPERATURE OF SOLDERING IRON	MAXIMUM SOLDERING TIME	DISTANCE FROM SOLDER JOINT TO CASE	
LEDS	≦260°C	3\$	>2 <b>mm</b>	≦260°C	38	>2 <b>mm</b>	
LLD3	≤260°C	58	>4 <b>mm</b>	≤260°C	58	>4 <b>mm</b>	
DISPLAYS	≤260°C	38	>2 <b>mm</b>	≤260°C	38	>2 <b>mm</b>	

APPROVE:	CHECKED:	DRAWN:	DATA NO:	SCALE: 4:1
Lin	Simon	Cui	P-O-BA-00001-03	DATE: oct,26,02





#### **SMD HANDLING AND APPLICATION PRECAUTIONS**

#### **STORAGE**

(1.1) It is recommended to store the devices in accordance with the following conditions:

Humidity:60%RH Max.

Temperature:  $5^{\circ}\text{C} \sim 30^{\circ}\text{C} (41^{\circ}\text{F} \sim 86^{\circ}\text{F})$ 

(1.2)Shelf life in sealed bag: 12 month at  $<5^{\circ}\text{C} \sim 30^{\circ}\text{C}$  and <30%RH. After the package is opened, the products should be used within 72hrs. Or they should be kept at  $\leq 20\%\text{RH}$  in zip-locked sealed bags.

#### DRY PACK AND BAKING

SMD LEDs are MOISTURE SENSITIVE devices. Avoid absorbing moisture at any time during transportation and/or sotrage. It is recommended to bake before soldering when the pack is unsealed after 72 hrs, or any suspicious moisture being found. Bake devices in accordance with the following conditions:

- (a)  $60\pm3^{\circ}$ C x  $(12\sim24\text{hrs})$  and <5%RH, taped reel type
- (b)  $100\pm3^{\circ}$ C x (45min~1hr), loose packing type, or
- (c)  $130\pm3^{\circ}$ C x  $(15\sim30\text{min})$ , loose packing type

#### **ELECTRIC STATIC DISCHARGE(ESD) PROTECTION**

Materials with GaN, InGaN, AlInGaP are STATIC SENSITIVE devices. They will be packed in anti-static bags. ESD protection must be deliberatively observed from the initial design stage. The static-electric discharge may result in severe malfunction of the devices. In the events of manual working in process, make sure the devices are well protected from ESD at any time. Surge before and during handling products.

APPROVE:	CHECKED:	DRAWN:	DATA NO:	SCALE: 4:1
Lin	Simon	Cui	P-O-BA-00001-04	<b>DATE:</b> DEC,11,02